

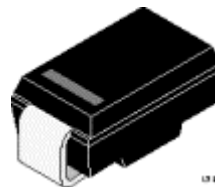


Schottky Diode (FH1N5822)

肖特基二极管

Features 特征:

- Ideal for surface mounted applications
 - Low leakage current.
 - For use in low voltage, high frequency inverters free wheeling, and polarity protection applications.
- SMB (DO-214AA)



3.0Ampere Schottky Barrier Rectifiers

3.0 安培肖特基势垒整流二极管

Absolute Maximum Ratings* 最大绝对值

T_A=25 unless otherwise noted

Symbol 符号	Parameter 参数	Value	Unites
I _{F(AV)}	Average Rectified Current 平均整流电流	3.0	A
I _{FSM}	Non-repetitive Peak Forward Surge Current 无重复正向峰值浪涌电流 8.3 ms single half-sine-wave superimposed on rated load	80	A
P _D	Total Device Dissipation 总耗散功率 Derate above 25	1.25 12.5	W MW/
R _{JA}	Thermal Resistance, Junction to Ambient 热阻	20	/W
T _{STG}	Storage Temperature Range 储存温度	-65 to +150	
T _J	Operating Junction Temperature 工作结温	-65 to +150	

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics T_A=25 unless otherwise noted

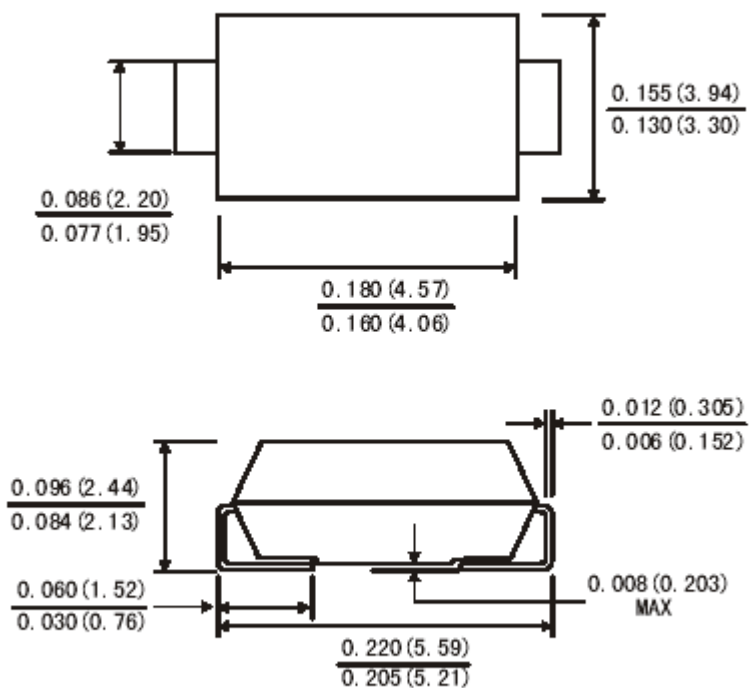
Symbol 符号	Parameter 参数	Value	Units
V _{RRM}	Maximum Peak Repetitive Reverse Voltage 最大峰值反向电压	40	V
V _{RMS}	Maximum RMS Voltage	28	V
V _R	DC Reverse Voltage (Rated V _R)反向电压	40	V
I _{RM}	Maximum Instantaneous Reverse Current 最大瞬间反向电流 T _A =25 @rated V _R T _A =100	0.5 10	mA mA
V _{FM}	Maximum Instantaneous Forward Voltage 最大瞬间正向电压 @1.0A	500	mV
C	Typical Junction capacitance 典型结容	300	pF



DO - 214AA Dimensions in INCHES(MILLIMETERS)

DO - 214AA 尺寸 英寸 (毫米)

DO214-AA



Dimensions in inches and (millimeters)